



Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from,Europe,America and south Asia,supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of “Quality Parts,Customers Priority,Honest Operation,and Considerate Service”,our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China

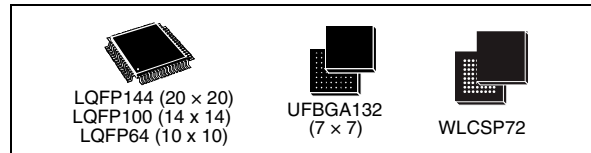


Ultra-low-power ARM[®] Cortex[®]-M4 32-bit MCU+FPU, 100DMIPS, up to 1MB Flash, 128KB SRAM, USB OTG FS, LCD, analog, audio, AES

Datasheet - production data

Features

- Ultra-low-power with FlexPowerControl
 - 1.71 V to 3.6 V power supply
 - -40 °C to 85/105/125 °C temperature range
 - 300 nA in V_{BAT} mode: supply for RTC and 32x32-bit backup registers
 - 30 nA Shutdown mode (5 wakeup pins)
 - 120 nA Standby mode (5 wakeup pins)
 - 420 nA Standby mode with RTC
 - 1.1 µA Stop 2 mode, 1.4 µA Stop 2 with RTC
 - 100 µA/MHz run mode
 - Batch acquisition mode (BAM)
 - 4 µs wakeup from Stop mode
 - Brown out reset (BOR) in all modes except shutdown
 - Interconnect matrix
- Core: ARM[®] 32-bit Cortex[®]-M4 CPU with FPU, Adaptive real-time accelerator (ART Accelerator™) allowing 0-wait-state execution from Flash memory, frequency up to 80 MHz, MPU, 100DMIPS/1.25DMIPS/MHz (Dhrystone 2.1), and DSP instructions
- Clock Sources
 - 4 to 48 MHz crystal oscillator
 - 32 kHz crystal oscillator for RTC (LSE)
 - Internal 16 MHz factory-trimmed RC (±1%)
 - Internal low-power 32 kHz RC (±5%)
 - Internal multispeed 100 kHz to 48 MHz oscillator, auto-trimmed by LSE (better than ±0.25 % accuracy)
 - 3 PLLs for system clock, USB, audio, ADC
- RTC with HW calendar, alarms and calibration
- LCD 8 × 40 or 4 × 44 with step-up converter
- Up to 24 capacitive sensing channels: support touchkey, linear and rotary touch sensors
- 16x timers: 2 x 16-bit advanced motor-control, 2 x 32-bit and 5 x 16-bit general purpose, 2x



16-bit basic, 2x low-power 16-bit timers (available in Stop mode), 2x watchdogs, SysTick timer

- Up to 114 fast I/Os, most 5 V-tolerant, up to 14 I/Os with independent supply down to 1.08 V
- Memories
 - 1 MB Flash, 2 banks read-while-write, proprietary code readout protection
 - 128 KB of SRAM including 32 KB with hardware parity check
 - External memory interface for static memories supporting SRAM, PSRAM, NOR and NAND memories
 - Quad SPI memory interface
- 4x digital filters for sigma delta modulator
- Rich analog peripherals (independent supply)
 - 3× 12-bit ADC 5 Msps, up to 16-bit with hardware oversampling, 200 µA/Msps
 - 2x 12-bit DAC, low-power sample and hold
 - 2x operational amplifiers with built-in PGA
 - 2x ultra-low-power comparators
- 19x communication interfaces
 - USB OTG 2.0 full-speed, LPM and BCD
 - 2x SAIs (serial audio interface)
 - 3x I2C FM+(1 Mbit/s), SMBus/PMBus
 - 6x USARTs (ISO 7816, LIN, IrDA, modem)
 - 3x SPIs (4x SPIs with the Quad SPI)
 - CAN (2.0B Active) and SDMMC interface
 - SWPMI single wire protocol master I/F
 - IRTIM (Infrared interface)
- 14-channel DMA controller
- True random number generator
- CRC calculation unit, 96-bit unique ID

-
- AES: 128/256-bit key encryption hardware accelerator
 - Development support: serial wire debug (SWD), JTAG, Embedded Trace Macrocell™

Table 1. Device summary

Reference	Part numbers
STM32L486xx	STM32L486JG, STM32L486QG, STM32L486RG, STM32L486VG, STM32L486ZG

Contents

1	Introduction	12
2	Description	13
3	Functional overview	17
3.1	ARM® Cortex®-M4 core with FPU	17
3.2	Adaptive real-time memory accelerator (ART Accelerator™)	17
3.3	Memory protection unit	17
3.4	Embedded Flash memory	18
3.5	Embedded SRAM	19
3.6	Firewall	19
3.7	Boot modes	20
3.8	Cyclic redundancy check calculation unit (CRC)	20
3.9	Power supply management	20
3.9.1	Power supply schemes	20
3.9.2	Power supply supervisor	21
3.9.3	Voltage regulator	22
3.9.4	Low-power modes	22
3.9.5	Reset mode	30
3.9.6	VBAT operation	30
3.10	Interconnect matrix	31
3.11	Clocks and startup	33
3.12	General-purpose inputs/outputs (GPIOs)	36
3.13	Direct memory access controller (DMA)	36
3.14	Interrupts and events	37
3.14.1	Nested vectored interrupt controller (NVIC)	37
3.14.2	Extended interrupt/event controller (EXTI)	37
3.15	Analog to digital converter (ADC)	38
3.15.1	Temperature sensor	38
3.15.2	Internal voltage reference (VREFINT)	39
3.15.3	VBAT battery voltage monitoring	39
3.16	Digital to analog converter (DAC)	39

3.17	Voltage reference buffer (VREFBUF)	40
3.18	Comparators (COMP)	40
3.19	Operational amplifier (OPAMP)	41
3.20	Touch sensing controller (TSC)	41
3.21	Liquid crystal display controller (LCD)	42
3.22	Digital filter for Sigma-Delta Modulators (DFSDM)	42
3.23	Random number generator (RNG)	43
3.24	Advanced encryption standard hardware accelerator (AES)	43
3.25	Timers and watchdogs	44
3.25.1	Advanced-control timer (TIM1, TIM8)	45
3.25.2	General-purpose timers (TIM2, TIM3, TIM4, TIM5, TIM15, TIM16, TIM17)	46
3.25.3	Basic timers (TIM6 and TIM7)	46
3.25.4	Low-power timer (LPTIM1 and LPTIM2)	46
3.25.5	Infrared interface (IRTIM)	47
3.25.6	Independent watchdog (IWDG)	47
3.25.7	System window watchdog (WWDG)	47
3.25.8	SysTick timer	47
3.26	Real-time clock (RTC) and backup registers	48
3.27	Inter-integrated circuit interface (I ² C)	49
3.28	Universal synchronous/asynchronous receiver transmitter (USART)	50
3.29	Low-power universal asynchronous receiver transmitter (LPUART)	51
3.30	Serial peripheral interface (SPI)	52
3.31	Serial audio interfaces (SAI)	52
3.32	Single wire protocol master interface (SWPMI)	53
3.33	Controller area network (CAN)	53
3.34	Secure digital input/output and MultiMediaCards Interface (SDMMC)	54
3.35	Universal serial bus on-the-go full-speed (OTG_FS)	54
3.36	Flexible static memory controller (FSMC)	55
3.37	Quad SPI memory interface (QUADSPI)	56
3.38	Development support	57
3.38.1	Serial wire JTAG debug port (SWJ-DP)	57
3.38.2	Embedded Trace Macrocell™	57
4	Pinouts and pin description	58

5	Memory mapping	90
6	Electrical characteristics	95
6.1	Parameter conditions	95
6.1.1	Minimum and maximum values	95
6.1.2	Typical values	95
6.1.3	Typical curves	95
6.1.4	Loading capacitor	95
6.1.5	Pin input voltage	95
6.1.6	Power supply scheme	96
6.1.7	Current consumption measurement	97
6.2	Absolute maximum ratings	97
6.3	Operating conditions	99
6.3.1	General operating conditions	99
6.3.2	Operating conditions at power-up / power-down	100
6.3.3	Embedded reset and power control block characteristics	100
6.3.4	Embedded voltage reference	103
6.3.5	Supply current characteristics	105
6.3.6	Wakeup time from low-power modes and voltage scaling transition times	126
6.3.7	External clock source characteristics	128
6.3.8	Internal clock source characteristics	133
6.3.9	PLL characteristics	138
6.3.10	Flash memory characteristics	139
6.3.11	EMC characteristics	141
6.3.12	Electrical sensitivity characteristics	142
6.3.13	I/O current injection characteristics	143
6.3.14	I/O port characteristics	144
6.3.15	NRST pin characteristics	150
6.3.16	Analog switches booster	151
6.3.17	Analog-to-Digital converter characteristics	152
6.3.18	Digital-to-Analog converter characteristics	165
6.3.19	Voltage reference buffer characteristics	169
6.3.20	Comparator characteristics	171
6.3.21	Operational amplifiers characteristics	172
6.3.22	Temperature sensor characteristics	175
6.3.23	V _{BAT} monitoring characteristics	175

	6.3.24	LCD controller characteristics	176
	6.3.25	DFSDM characteristics	178
	6.3.26	Timer characteristics	179
	6.3.27	Communication interfaces characteristics	181
	6.3.28	FSMC characteristics	192
	6.3.29	SWPMI characteristics	209
7		Package information	210
	7.1	LQFP144 package information	210
	7.2	UFBGA132 package information	214
	7.3	LQFP100 package information	217
	7.4	WLCSP72 package information	220
	7.5	LQFP64 package information	223
	7.6	Thermal characteristics	226
	7.6.1	Reference document	226
	7.6.2	Selecting the product temperature range	226
8		Part numbering	229
9		Revision history	230

List of tables

Table 1.	Device summary	2
Table 2.	STM32L486xx family device features and peripheral counts	14
Table 3.	Access status versus readout protection level and execution modes.	18
Table 4.	STM32L486xx modes overview	23
Table 5.	Functionalities depending on the working mode.	28
Table 6.	STM32L486xx peripherals interconnect matrix	31
Table 7.	DMA implementation	36
Table 8.	Temperature sensor calibration values.	39
Table 9.	Internal voltage reference calibration values	39
Table 10.	Timer feature comparison.	44
Table 11.	I2C implementation.	49
Table 12.	STM32L486xx USART/UART/LPUART features	50
Table 13.	SAI implementation.	53
Table 14.	Legend/abbreviations used in the pinout table	61
Table 15.	STM32L486xx pin definitions	62
Table 16.	Alternate function AF0 to AF7 (for AF8 to AF15 see Table 17)	75
Table 17.	Alternate function AF8 to AF15 (for AF0 to AF7 see Table 16)	82
Table 18.	STM32L486xx memory map and peripheral register boundary addresses	91
Table 19.	Voltage characteristics	97
Table 20.	Current characteristics	98
Table 21.	Thermal characteristics.	98
Table 22.	General operating conditions	99
Table 23.	Operating conditions at power-up / power-down	100
Table 24.	Embedded reset and power control block characteristics.	101
Table 25.	Embedded internal voltage reference.	103
Table 26.	Current consumption in Run and Low-power run modes, code with data processing running from Flash, ART enable (Cache ON Prefetch OFF)	106
Table 27.	Current consumption in Run and Low-power run modes, code with data processing running from Flash, ART disable	107
Table 28.	Current consumption in Run and Low-power run modes, code with data processing running from SRAM1	108
Table 29.	Typical current consumption in Run and Low-power run modes, with different codes running from Flash, ART enable (Cache ON Prefetch OFF)	109
Table 30.	Typical current consumption in Run and Low-power run modes, with different codes running from Flash, ART disable	109
Table 31.	Typical current consumption in Run and Low-power run modes, with different codes running from SRAM1	110
Table 32.	Current consumption in Sleep and Low-power sleep modes, Flash ON	111
Table 33.	Current consumption in Low-power sleep modes, Flash in power-down	112
Table 34.	Current consumption in Stop 2 mode	112
Table 35.	Current consumption in Stop 1 mode	115
Table 36.	Current consumption in Stop 0 mode	117
Table 37.	Current consumption in Standby mode	118
Table 38.	Current consumption in Shutdown mode	119
Table 39.	Current consumption in VBAT mode	121
Table 40.	Peripheral current consumption	123
Table 41.	Low-power mode wakeup timings	126

Table 42.	Regulator modes transition times	128
Table 43.	Wakeup time using USART/LPUART	128
Table 44.	High-speed external user clock characteristics	128
Table 45.	Low-speed external user clock characteristics	129
Table 46.	HSE oscillator characteristics	130
Table 47.	LSE oscillator characteristics ($f_{LSE} = 32.768$ kHz)	131
Table 48.	HSI16 oscillator characteristics	133
Table 49.	MSI oscillator characteristics	135
Table 50.	LSI oscillator characteristics	138
Table 51.	PLL, PLLSAI1, PLLSAI2 characteristics	139
Table 52.	Flash memory characteristics	139
Table 53.	Flash memory endurance and data retention	140
Table 54.	EMS characteristics	141
Table 55.	EMI characteristics	142
Table 56.	ESD absolute maximum ratings	142
Table 57.	Electrical sensitivities	143
Table 58.	I/O current injection susceptibility	143
Table 59.	I/O static characteristics	144
Table 60.	Output voltage characteristics	147
Table 61.	I/O AC characteristics	148
Table 62.	NRST pin characteristics	150
Table 63.	Analog switches booster characteristics	151
Table 64.	ADC characteristics	152
Table 65.	Maximum ADC RAIN	154
Table 66.	ADC accuracy - limited test conditions 1	156
Table 67.	ADC accuracy - limited test conditions 2	158
Table 68.	ADC accuracy - limited test conditions 3	160
Table 69.	ADC accuracy - limited test conditions 4	162
Table 70.	DAC characteristics	165
Table 71.	DAC accuracy	167
Table 72.	VREFBUF characteristics	169
Table 73.	COMP characteristics	171
Table 74.	OPAMP characteristics	172
Table 75.	TS characteristics	175
Table 76.	V_{BAT} monitoring characteristics	175
Table 77.	V_{BAT} charging characteristics	175
Table 78.	LCD controller characteristics	176
Table 79.	DFSDM characteristics	178
Table 80.	TIMx characteristics	180
Table 81.	IWDG min/max timeout period at 32 kHz (LSI)	180
Table 82.	WWDG min/max timeout value at 80 MHz (PCLK)	180
Table 83.	I2C analog filter characteristics	181
Table 84.	SPI characteristics	182
Table 85.	Quad SPI characteristics in SDR mode	185
Table 86.	QUADSPI characteristics in DDR mode	186
Table 87.	SAI characteristics	187
Table 88.	SD / MMC dynamic characteristics, $V_{DD} = 2.7$ V to 3.6 V	189
Table 89.	eMMC dynamic characteristics, $V_{DD} = 1.71$ V to 1.9 V	190
Table 90.	USB electrical characteristics	191
Table 91.	Asynchronous non-multiplexed SRAM/PSRAM/NOR read timings	194
Table 92.	Asynchronous non-multiplexed SRAM/PSRAM/NOR read-NWAIT timings	194
Table 93.	Asynchronous non-multiplexed SRAM/PSRAM/NOR write timings	195

Table 94.	Asynchronous non-multiplexed SRAM/PSRAM/NOR write-NWAIT timings	196
Table 95.	Asynchronous multiplexed PSRAM/NOR read timings	197
Table 96.	Asynchronous multiplexed PSRAM/NOR read-NWAIT timings	197
Table 97.	Asynchronous multiplexed PSRAM/NOR write timings	199
Table 98.	Asynchronous multiplexed PSRAM/NOR write-NWAIT timings	199
Table 99.	Synchronous multiplexed NOR/PSRAM read timings	201
Table 100.	Synchronous multiplexed PSRAM write timings	203
Table 101.	Synchronous non-multiplexed NOR/PSRAM read timings	204
Table 102.	Synchronous non-multiplexed PSRAM write timings	206
Table 103.	Switching characteristics for NAND Flash read cycles	208
Table 104.	Switching characteristics for NAND Flash write cycles	208
Table 105.	SWPMI electrical characteristics	209
Table 106.	LQFP144 - 144-pin, 20 x 20 mm low-profile quad flat package mechanical data	211
Table 107.	UFBGA132 - 132-ball, 7 x 7 mm ultra thin fine pitch ball grid array package mechanical data	214
Table 108.	UFBGA132 recommended PCB design rules (0.5 mm pitch BGA)	215
Table 109.	LQFP100 - 100-pin, 14 x 14 mm low-profile quad flat package mechanical data	217
Table 110.	WLCSP72 - 72-ball, 4.4084 x 3.7594 mm, 0.4 mm pitch wafer level chip scale package mechanical data	220
Table 111.	WLCSP72 recommended PCB design rules (0.4 mm pitch BGA)	221
Table 112.	LQFP64 - 64-pin, 10 x 10 mm low-profile quad flat package mechanical data	223
Table 113.	Package thermal characteristics	226
Table 114.	STM32L486xx ordering information scheme	229
Table 115.	Document revision history	230

List of figures

Figure 1.	STM32L486xx block diagram	16
Figure 2.	Power supply overview	21
Figure 3.	Clock tree	35
Figure 4.	Voltage reference buffer	40
Figure 5.	STM32L486Zx LQFP144 pinout ⁽¹⁾	58
Figure 6.	STM32L486Qx UFBGA132 ballout ⁽¹⁾	59
Figure 7.	STM32L486Vx LQFP100 pinout ⁽¹⁾	59
Figure 8.	STM32L486Jx WLCSP72 ballout ⁽¹⁾	60
Figure 9.	STM32L486Rx LQFP64 pinout ⁽¹⁾	60
Figure 10.	STM32L486xx memory map	90
Figure 11.	Pin loading conditions	95
Figure 12.	Pin input voltage	95
Figure 13.	Power supply scheme	96
Figure 14.	Current consumption measurement scheme	97
Figure 15.	VREFINT versus temperature	104
Figure 16.	High-speed external clock source AC timing diagram	129
Figure 17.	Low-speed external clock source AC timing diagram	129
Figure 18.	Typical application with an 8 MHz crystal	131
Figure 19.	Typical application with a 32.768 kHz crystal	132
Figure 20.	HSI16 frequency versus temperature	134
Figure 21.	Typical current consumption versus MSI frequency	138
Figure 22.	I/O input characteristics	146
Figure 23.	I/O AC characteristics definition ⁽¹⁾	150
Figure 24.	Recommended NRST pin protection	151
Figure 25.	ADC accuracy characteristics	164
Figure 26.	Typical connection diagram using the ADC	164
Figure 27.	12-bit buffered / non-buffered DAC	167
Figure 28.	SPI timing diagram - slave mode and CPHA = 0	183
Figure 29.	SPI timing diagram - slave mode and CPHA = 1	184
Figure 30.	SPI timing diagram - master mode	184
Figure 31.	Quad SPI timing diagram - SDR mode	186
Figure 32.	Quad SPI timing diagram - DDR mode	186
Figure 33.	SAI master timing waveforms	188
Figure 34.	SAI slave timing waveforms	189
Figure 35.	SDIO high-speed mode	190
Figure 36.	SD default mode	191
Figure 37.	Asynchronous non-multiplexed SRAM/PSRAM/NOR read waveforms	193
Figure 38.	Asynchronous non-multiplexed SRAM/PSRAM/NOR write waveforms	195
Figure 39.	Asynchronous multiplexed PSRAM/NOR read waveforms	196
Figure 40.	Asynchronous multiplexed PSRAM/NOR write waveforms	198
Figure 41.	Synchronous multiplexed NOR/PSRAM read timings	200
Figure 42.	Synchronous multiplexed PSRAM write timings	202
Figure 43.	Synchronous non-multiplexed NOR/PSRAM read timings	204
Figure 44.	Synchronous non-multiplexed PSRAM write timings	205
Figure 45.	NAND controller waveforms for read access	207
Figure 46.	NAND controller waveforms for write access	207
Figure 47.	NAND controller waveforms for common memory read access	207
Figure 48.	NAND controller waveforms for common memory write access	208

Figure 49.	LQFP144 - 144-pin, 20 x 20 mm low-profile quad flat package outline	210
Figure 50.	LQFP144 - 144-pin, 20 x 20 mm low-profile quad flat package recommended footprint.	212
Figure 51.	LQFP144 marking (package top view)	213
Figure 52.	UFBGA132 - 132-ball, 7 x 7 mm ultra thin fine pitch ball grid array package outline.	214
Figure 53.	UFBGA132 - 132-ball, 7 x 7 mm ultra thin fine pitch ball grid array package recommended footprint	215
Figure 54.	UFBGA132 marking (package top view)	216
Figure 55.	LQFP100 - 100-pin, 14 x 14 mm low-profile quad flat package outline	217
Figure 56.	LQFP100 - 100-pin, 14 x 14 mm low-profile quad flat recommended footprint.	218
Figure 57.	LQFP100 marking (package top view)	219
Figure 58.	WLCSP72 - 72-ball, 4.4084 x 3.7594 mm, 0.4 mm pitch wafer level chip scale package outline	220
Figure 59.	WLCSP72 - 72-ball, 4.4084 x 3.7594 mm, 0.4 mm pitch wafer level chip scale package recommended footprint.	221
Figure 60.	WLCSP72 marking (package top view)	222
Figure 61.	LQFP64 - 64-pin, 10 x 10 mm low-profile quad flat package outline	223
Figure 62.	LQFP64 - 64-pin, 10 x 10 mm low-profile quad flat package recommended footprint.	224
Figure 63.	LQFP64 marking (package top view)	225
Figure 64.	LQFP64 P_D max vs. T_A	228

1 Introduction

This datasheet provides the ordering information and mechanical device characteristics of the STM32L486xx microcontrollers.

This document should be read in conjunction with the STM32L4x6 reference manual (RM0351). The reference manual is available from the STMicroelectronics website www.st.com.

For information on the ARM® Cortex®-M4 core, please refer to the Cortex®-M4 Technical Reference Manual, available from the www.arm.com website.



2 Description

The STM32L486xx devices are the ultra-low-power microcontrollers based on the high-performance ARM[®] Cortex[®]-M4 32-bit RISC core operating at a frequency of up to 80 MHz. The Cortex-M4 core features a Floating point unit (FPU) single precision which supports all ARM single-precision data-processing instructions and data types. It also implements a full set of DSP instructions and a memory protection unit (MPU) which enhances application security.

The STM32L486xx devices embed high-speed memories (1 Mbyte of Flash memory, 128 Kbyte of SRAM), a flexible external memory controller (FSMC) for static memories (for devices with packages of 100 pins and more), a Quad SPI flash memories interface (available on all packages) and an extensive range of enhanced I/Os and peripherals connected to two APB buses, two AHB buses and a 32-bit multi-AHB bus matrix.

The STM32L486xx devices embed several protection mechanisms for embedded Flash memory and SRAM: readout protection, write protection, proprietary code readout protection and Firewall.

The devices offer up to three fast 12-bit ADCs (5 Msps), two comparators, two operational amplifiers, two DAC channels, an internal voltage reference buffer, a low-power RTC, two general-purpose 32-bit timer, two 16-bit PWM timers dedicated to motor control, seven general-purpose 16-bit timers, and two 16-bit low-power timers. The devices support four digital filters for external sigma delta modulators (DFSDM).

In addition, up to 24 capacitive sensing channels are available. The devices also embed an integrated LCD driver 8x40 or 4x44, with internal step-up converter.

They also feature standard and advanced communication interfaces.

- Three I2Cs
- Three SPIs
- Three USARTs, two UARTs and one Low-Power UART.
- Two SAIs (Serial Audio Interfaces)
- One SDMMC
- One CAN
- One USB OTG full-speed
- One SWPMI (Single Wire Protocol Master Interface)

The STM32L486xx devices embed AES hardware accelerator.

The STM32L486xx operates in the -40 to +85 °C (+105 °C junction), -40 to +105 °C (+125 °C junction) and -40 to +125 °C (+130 °C junction) temperature ranges from a 1.71 to 3.6 V power supply. A comprehensive set of power-saving modes allows the design of low-power applications.

Some independent power supplies are supported: analog independent supply input for ADC, DAC, OPAMPs and comparators, 3.3 V dedicated supply input for USB and up to 14 I/Os can be supplied independently down to 1.08V_A. A VBAT input allows to backup the RTC and backup registers.

The STM32L486xx family offers five packages from 64-pin to 144-pin packages.

Table 2. STM32L486xx family device features and peripheral counts

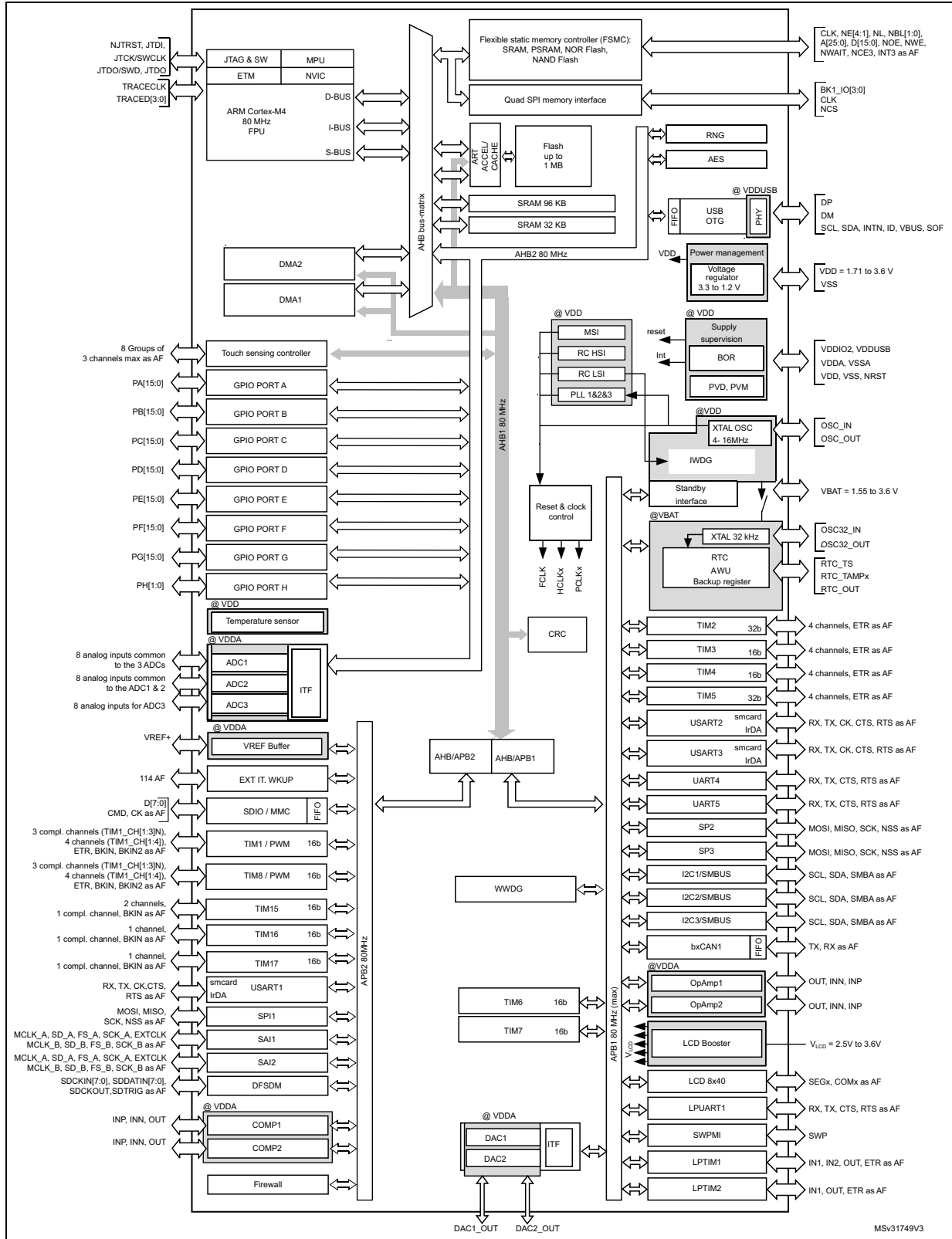
Peripheral		STM32L486Zx	STM32L486Qx	STM32L486Vx	STM32L486Jx	STM32L486Rx
Flash memory		1 MB				
SRAM		128 KB				
External memory controller for static memories		Yes	Yes	Yes ⁽¹⁾	No	No
Quad SPI		Yes				
Timers	Advanced control	2 (16-bit)				
	General purpose	5 (16-bit) 2 (32-bit)				
	Basic	2 (16-bit)				
	Low power	2 (16-bit)				
	SysTick timer	1				
	Watchdog timers (independent , window)	2				
Comm. interfaces	SPI	3				
	I ² C	3				
	USART	3				
	UART	2				
	LPUART	1				
	SAI	2				
	CAN	1				
	USB OTG FS	Yes				
SDMMC	Yes					
SWPMI	Yes					
Digital filters for sigma-delta modulators		Yes (4 filters)				
Number of channels		8				
RTC		Yes				
Tamper pins		3			2	2
LCD COM x SEG	Yes 8x40 or 4x44	Yes 8x40 or 4x44	Yes 8x40 or 4x44	Yes 8x28 or 4x32	Yes 8x28 or 4x32	Yes 8x28 or 4x32
Random generator		Yes				
AES		Yes				

Table 2. STM32L486xx family device features and peripheral counts (continued)

Peripheral	STM32L486Zx	STM32L486Qx	STM32L486Vx	STM32L486Jx	STM32L486Rx
GPIOs	114	109	82	57	51
Wakeup pins	5	5	5	4	4
Nb of I/Os down to 1.08 V	14	14	0	6	0
Capacitive sensing Number of channels	24	24	21	12	12
12-bit ADCs Number of channels	3 24	3 19	3 16	3 16	3 16
12-bit DAC channels	2				
Internal voltage reference buffer	Yes				No
Analog comparator	2				
Operational amplifiers	2				
Max. CPU frequency	80 MHz				
Operating voltage	1.71 to 3.6 V				
Operating temperature	Ambient operating temperature: -40 to 85 °C / -40 to 105 °C / -40 to 125 °C Junction temperature: -40 to 105 °C / -40 to 125 °C / -40 to 130 °C				
Packages	LQFP144	UFBGA132	LQFP100	WLCSP72	LQFP64

1. For the LQFP100 package, only FMC Bank1 is available. Bank1 can only support a multiplexed NOR/PSRAM memory using the NE1 Chip Select.

Figure 1. STM32L486xx block diagram



Note: AF: alternate function on I/O pins.



3 Functional overview

3.1 ARM[®] Cortex[®]-M4 core with FPU

The ARM[®] Cortex[®]-M4 with FPU processor is the latest generation of ARM processors for embedded systems. It was developed to provide a low-cost platform that meets the needs of MCU implementation, with a reduced pin count and low-power consumption, while delivering outstanding computational performance and an advanced response to interrupts.

The ARM[®] Cortex[®]-M4 with FPU 32-bit RISC processor features exceptional code-efficiency, delivering the high-performance expected from an ARM core in the memory size usually associated with 8- and 16-bit devices.

The processor supports a set of DSP instructions which allow efficient signal processing and complex algorithm execution.

Its single precision FPU speeds up software development by using metalanguage development tools, while avoiding saturation.

With its embedded ARM core, the STM32L486xx family is compatible with all ARM tools and software.

Figure 1 shows the general block diagram of the STM32L486xx family devices.

3.2 Adaptive real-time memory accelerator (ART Accelerator™)

The ART Accelerator™ is a memory accelerator which is optimized for STM32 industry-standard ARM[®] Cortex[®]-M4 processors. It balances the inherent performance advantage of the ARM[®] Cortex[®]-M4 over Flash memory technologies, which normally requires the processor to wait for the Flash memory at higher frequencies.

To release the processor near 100 DMIPS performance at 80MHz, the accelerator implements an instruction prefetch queue and branch cache, which increases program execution speed from the 64-bit Flash memory. Based on CoreMark benchmark, the performance achieved thanks to the ART accelerator is equivalent to 0 wait state program execution from Flash memory at a CPU frequency up to 80 MHz.

3.3 Memory protection unit

The memory protection unit (MPU) is used to manage the CPU accesses to memory to prevent one task to accidentally corrupt the memory or resources used by any other active task. This memory area is organized into up to 8 protected areas that can in turn be divided up into 8 subareas. The protection area sizes are between 32 bytes and the whole 4 gigabytes of addressable memory.

The MPU is especially helpful for applications where some critical or certified code has to be protected against the misbehavior of other tasks. It is usually managed by an RTOS (real-time operating system). If a program accesses a memory location that is prohibited by the MPU, the RTOS can detect it and take action. In an RTOS environment, the kernel can dynamically update the MPU area setting, based on the process to be executed.

The MPU is optional and can be bypassed for applications that do not need it.

3.4 Embedded Flash memory

STM32L486xx devices feature 1 Mbyte of embedded Flash memory available for storing programs and data. The Flash memory is divided into two banks allowing read-while-write operations. This feature allows to perform a read operation from one bank while an erase or program operation is performed to the other bank. The dual bank boot is also supported. Each bank contains 256 pages of 2 Kbyte.

Flexible protections can be configured thanks to option bytes:

- Readout protection (RDP) to protect the whole memory. Three levels are available:
 - Level 0: no readout protection
 - Level 1: memory readout protection: the Flash memory cannot be read from or written to if either debug features are connected, boot in RAM or bootloader is selected
 - Level 2: chip readout protection: debug features (Cortex-M4 JTAG and serial wire), boot in RAM and bootloader selection are disabled (JTAG fuse). This selection is irreversible.

Table 3. Access status versus readout protection level and execution modes

Area	Protection level	User execution			Debug, boot from RAM or boot from system memory (loader)		
		Read	Write	Erase	Read	Write	Erase
Main memory	1	Yes	Yes	Yes	No	No	No
	2	Yes	Yes	Yes	N/A	N/A	N/A
System memory	1	Yes	No	No	Yes	No	No
	2	Yes	No	No	N/A	N/A	N/A
Option bytes	1	Yes	Yes	Yes	Yes	Yes	Yes
	2	Yes	No	No	N/A	N/A	N/A
Backup registers	1	Yes	Yes	N/A ⁽¹⁾	No	No	N/A ⁽¹⁾
	2	Yes	Yes	N/A	N/A	N/A	N/A
SRAM2	1	Yes	Yes	Yes ⁽¹⁾	No	No	No ⁽¹⁾
	2	Yes	Yes	Yes	N/A	N/A	N/A

1. Erased when RDP change from Level 1 to Level 0.

- Write protection (WRP): the protected area is protected against erasing and programming. Two areas per bank can be selected, with 2-Kbyte granularity.
- Proprietary code readout protection (PCROP): a part of the flash memory can be protected against read and write from third parties. The protected area is execute-only: it can only be reached by the STM32 CPU, as an instruction code, while all other accesses (DMA, debug and CPU data read, write and erase) are strictly prohibited. One area per bank can be selected, with 64-bit granularity. An additional option bit (PCROP_RDP) allows to select if the PCROP area is erased or not when the RDP protection is changed from Level 1 to Level 0.

The whole non-volatile memory embeds the error correction code (ECC) feature supporting:

- single error detection and correction
- double error detection.
- The address of the ECC fail can be read in the ECC register

3.5 Embedded SRAM

STM32L486xx devices feature 128 Kbyte of embedded SRAM. This SRAM is split into two blocks:

- 96 Kbyte mapped at address 0x2000 0000 (SRAM1)
- 32 Kbyte located at address 0x1000 0000 with hardware parity check (SRAM2).
This block is accessed through the ICode/DCode buses for maximum performance. These 32 Kbyte SRAM can also be retained in Standby mode.
The SRAM2 can be write-protected with 1 Kbyte granularity.

The memory can be accessed in read/write at CPU clock speed with 0 wait states.

3.6 Firewall

The device embeds a Firewall which protects code sensitive and secure data from any access performed by a code executed outside of the protected areas.

Each illegal access generates a reset which kills immediately the detected intrusion.

The Firewall main features are the following:

- Three segments can be protected and defined thanks to the Firewall registers:
 - Code segment (located in Flash or SRAM1 if defined as executable protected area)
 - Non-volatile data segment (located in Flash)
 - Volatile data segment (located in SRAM1)
- The start address and the length of each segments are configurable:
 - code segment: up to 1024 Kbyte with granularity of 256 bytes
 - Non-volatile data segment: up to 1024 Kbyte with granularity of 256 bytes
 - Volatile data segment: up to 96 Kbyte with a granularity of 64 bytes
- Specific mechanism implemented to open the Firewall to get access to the protected areas (call gate entry sequence)
- Volatile data segment can be shared or not with the non-protected code
- Volatile data segment can be executed or not depending on the Firewall configuration

The Flash readout protection must be set to level 2 in order to reach the expected level of protection.

3.7 Boot modes

At startup, BOOT0 pin and BOOT1 option bit are used to select one of three boot options:

- Boot from user Flash
- Boot from system memory
- Boot from embedded SRAM

The boot loader is located in system memory. It is used to reprogram the Flash memory by using USART, I2C, SPI, CAN and USB OTG FS in Device mode through DFU (device firmware upgrade).

3.8 Cyclic redundancy check calculation unit (CRC)

The CRC (cyclic redundancy check) calculation unit is used to get a CRC code using a configurable generator polynomial value and size.

Among other applications, CRC-based techniques are used to verify data transmission or storage integrity. In the scope of the EN/IEC 60335-1 standard, they offer a means of verifying the Flash memory integrity. The CRC calculation unit helps compute a signature of the software during runtime, to be compared with a reference signature generated at link-time and stored at a given memory location.

3.9 Power supply management

3.9.1 Power supply schemes

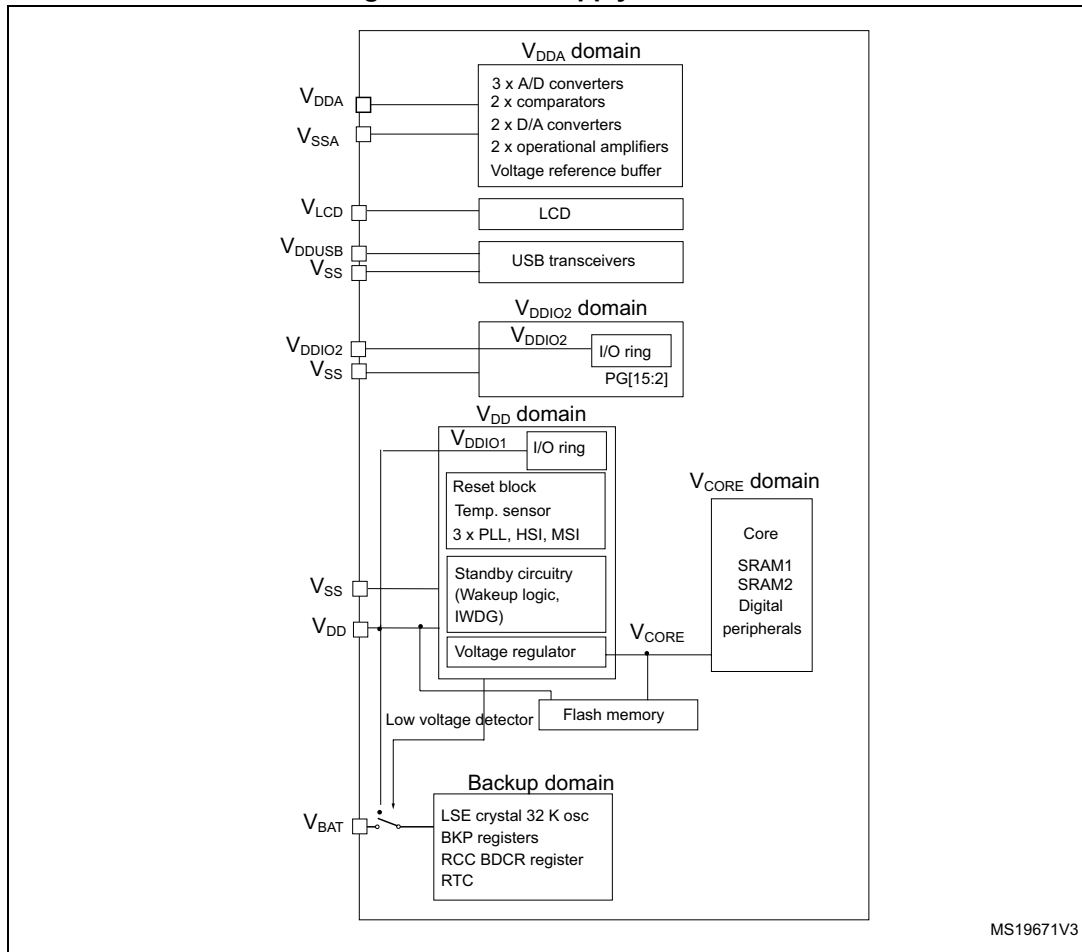
- $V_{DD} = 1.71$ to 3.6 V: external power supply for I/Os (V_{DDIO1}), the internal regulator and the system analog such as reset, power management and internal clocks. It is provided externally through V_{DD} pins.
- $V_{DDA} = 1.62$ V (ADCs/COMP) / 1.8 (DACs/OPAMP) to 3.6 V: external analog power supply for ADCs, DACs, OPAMPs, Comparators and Voltage reference buffer. The V_{DDA} voltage level is independent from the V_{DD} voltage.
- $V_{DDUSB} = 3.0$ to 3.6 V: external independent power supply for USB transceivers. The V_{DDUSB} voltage level is independent from the V_{DD} voltage.
- $V_{DDIO2} = 1.08$ to 3.6 V: external power supply for 14 I/Os (PG[15:2]). The V_{DDIO2} voltage level is independent from the V_{DD} voltage.
- $V_{LCD} = 2.5$ to 3.6 V: the LCD controller can be powered either externally through VLCD pin, or internally from an internal voltage generated by the embedded step-up converter.
- $V_{BAT} = 1.55$ to 3.6 V: power supply for RTC, external clock 32 kHz oscillator and backup registers (through power switch) when V_{DD} is not present.

Note: When the functions supplied by V_{DDA} , V_{DDUSB} or V_{DDIO2} are not used, these supplies should preferably be shorted to V_{DD} .

Note: If these supplies are tied to ground, the I/Os supplied by these power supplies are not 5 V tolerant (refer to [Table 19: Voltage characteristics](#)).

Note: V_{DDIOx} is the I/Os general purpose digital functions supply. V_{DDIOx} represents V_{DDIO1} or V_{DDIO2} , with $V_{DDIO1} = V_{DD}$. V_{DDIO2} supply voltage level is independent from V_{DDIO1} .

Figure 2. Power supply overview



MS19671V3

3.9.2 Power supply supervisor

The device has an integrated ultra-low-power brown-out reset (BOR) active in all modes except Shutdown and ensuring proper operation after power-on and during power down. The device remains in reset mode when the monitored supply voltage V_{DD} is below a specified threshold, without the need for an external reset circuit.

The lowest BOR level is 1.71V at power on, and other higher thresholds can be selected through option bytes. The device features an embedded programmable voltage detector (PVD) that monitors the V_{DD} power supply and compares it to the VPVD threshold. An interrupt can be generated when V_{DD} drops below the VPVD threshold and/or when V_{DD} is higher than the VPVD threshold. The interrupt service routine can then generate a warning message and/or put the MCU into a safe state. The PVD is enabled by software.

In addition, the device embeds a Peripheral Voltage Monitor which compares the independent supply voltages V_{DDA} , V_{DDUSB} , V_{DDIO2} with a fixed threshold in order to ensure that the peripheral is in its functional supply range.

3.9.3 Voltage regulator

Two embedded linear voltage regulators supply most of the digital circuitries: the main regulator (MR) and the low-power regulator (LPR).

- The MR is used in the Run and Sleep modes and in the Stop 0 mode.
- The LPR is used in Low-Power Run, Low-Power Sleep, Stop 1 and Stop 2 modes. It is also used to supply the 32 Kbyte SRAM2 in Standby with RAM2 retention.
- Both regulators are in power-down in Standby and Shutdown modes: the regulator output is in high impedance, and the kernel circuitry is powered down thus inducing zero consumption.

The ultralow-power STM32L486xx supports dynamic voltage scaling to optimize its power consumption in run mode. The voltage from the Main Regulator that supplies the logic (VCORE) can be adjusted according to the system's maximum operating frequency.

There are two power consumption ranges:

- Range 1 with the CPU running at up to 80 MHz.
- Range 2 with a maximum CPU frequency of 26 MHz. All peripheral clocks are also limited to 26 MHz.

The VCORE can be supplied by the low-power regulator, the main regulator being switched off. The system is then in Low-power run mode.

- Low-power run mode with the CPU running at up to 2 MHz. Peripherals with independent clock can be clocked by HSI16.

3.9.4 Low-power modes

The ultra-low-power STM32L486xx supports seven low-power modes to achieve the best compromise between low-power consumption, short startup time, available peripherals and available wakeup sources:

Table 4. STM32L486xx modes overview

Mode	Regulator ⁽¹⁾	CPU	Flash	SRAM	Clocks	DMA & Peripherals ⁽²⁾	Wakeup source	Consumption ⁽³⁾	Wakeup time
Run	Range 1	Yes	ON ⁽⁴⁾	ON	Any	All	N/A	112 μ A/MHz	N/A
	Range2					All except OTG_FS, RNG		100 μ A/MHz	
LPRun	LPR	Yes	ON ⁽⁴⁾	ON	Any except PLL	All except OTG_FS, RNG	N/A	136 μ A/MHz	to Range 1: 4 μ s to Range 2: 64 μ s
Sleep	Range 1	No	ON ⁽⁴⁾	ON ⁽⁵⁾	Any	All	Any interrupt or event	37 μ A/MHz	6 cycles
	Range 2					All except OTG_FS, RNG		35 μ A/MHz	6 cycles
LPSleep	LPR	No	ON ⁽⁴⁾	ON ⁽⁵⁾	Any except PLL	All except OTG_FS, RNG	Any interrupt or event	40 μ A/MHz	6 cycles
Stop 0	Range 1	No	Off	ON	LSE LSI	BOR, PVD, PVM RTC, LCD,IWDG COMPx (x=1,2) DACx (x=1,2) OPAMPx (x=1,2) USARTx (x=1...5) ⁽⁶⁾ LPUART1 ⁽⁶⁾ I2Cx (x=1...3) ⁽⁷⁾ LPTIMx (x=1,2) *** All other peripherals are frozen.	Reset pin, all I/Os BOR, PVD, PVM RTC, LCD,IWDG COMPx (x=1..2) USARTx (x=1...5) ⁽⁶⁾ LPUART1 ⁽⁶⁾ I2Cx (x=1...3) ⁽⁷⁾ LPTIMx (x=1,2) OTG_FS ⁽⁸⁾ SWPMI1 ⁽⁹⁾	108 μ A	0.7 μ s in SRAM 4.5 μ s in Flash
	Range 2								



Table 4. STM32L486xx modes overview (continued)

Mode	Regulator ⁽¹⁾	CPU	Flash	SRAM	Clocks	DMA & Peripherals ⁽²⁾	Wakeup source	Consumption ⁽³⁾	Wakeup time
Stop 1	LPR	No	Off	ON	LSE LSI	BOR, PVD, PVM RTC, LCD, IWDG COMPx (x=1,2) DACx (x=1,2) OPAMPx (x=1,2) USARTx (x=1...5) ⁽⁶⁾ LPUART1 ⁽⁶⁾ I2Cx (x=1...3) ⁽⁷⁾ LPTIMx (x=1,2) *** All other peripherals are frozen.	Reset pin, all I/Os BOR, PVD, PVM RTC, LCD, IWDG COMPx (x=1..2) USARTx (x=1...5) ⁽⁶⁾ LPUART1 ⁽⁶⁾ I2Cx (x=1...3) ⁽⁷⁾ LPTIMx (x=1,2) OTG_FS ⁽⁸⁾ SWPMI1 ⁽⁹⁾	6.6 μ A w/o RTC 6.9 μ A w RTC	4 μ s in SRAM 6 μ s in Flash
Stop 2	LPR	No	Off	ON	LSE LSI	BOR, PVD, PVM RTC, LCD, IWDG COMPx (x=1..2) I2C3 ⁽⁷⁾ LPUART1 ⁽⁶⁾ LPTIM1 *** All other peripherals are frozen.	Reset pin, all I/Os BOR, PVD, PVM RTC, LCD, IWDG COMPx (x=1..2) I2C3 ⁽⁷⁾ LPUART1 ⁽⁶⁾ LPTIM1	1.1 μ A w/o RTC 1.4 μ A w/RTC	5 μ s in SRAM 7 μ s in Flash

Table 4. STM32L486xx modes overview (continued)

Mode	Regulator ⁽¹⁾	CPU	Flash	SRAM	Clocks	DMA & Peripherals ⁽²⁾	Wakeup source	Consumption ⁽³⁾	Wakeup time
Standby	LPR	Powered Off	Off	SRAM2 ON	LSE LSI	BOR, RTC, IWDG ***	Reset pin 5 I/Os (WKUPx) ⁽¹⁰⁾ BOR, RTC, IWDG	0.35 μ A w/o RTC 0.65 μ A w/ RTC	14 μ s
	OFF			Powered Off		All other peripherals are powered off. *** I/O configuration can be floating, pull-up or pull-down		0.12 μ A w/o RTC 0.42 μ A w/ RTC	
Shutdown	OFF	Powered Off	Off	Powered Off	LSE	RTC *** All other peripherals are powered off. *** I/O configuration can be floating, pull-up or pull-down ⁽¹¹⁾	Reset pin 5 I/Os (WKUPx) ⁽¹⁰⁾ RTC	0.03 μ A w/o RTC 0.33 μ A w/ RTC	256 μ s

1. LPR means Main regulator is OFF and Low-power regulator is ON.
2. All peripherals can be active or clock gated to save power consumption.
3. Typical current at $V_{DD} = 1.8$ V, 25°C. Consumptions values provided running from SRAM, Flash memory Off, 80 MHz in Range 1, 26 MHz in Range 2, 2 MHz in LPRun/LPSleep.
4. The Flash memory can be put in power-down and its clock can be gated off when executing from SRAM.
5. The SRAM1 and SRAM2 clocks can be gated on or off independently.
6. U(S)ART and LPUART reception is functional in Stop mode, and generates a wakeup interrupt on Start, address match or received frame event.
7. I2C address detection is functional in Stop mode, and generates a wakeup interrupt in case of address match.
8. OTG_FS wakeup by resume from suspend and attach detection protocol event.
9. SWPMI1 wakeup by resume from suspend.
10. The I/Os with wakeup from Standby/Shutdown capability are: PA0, PC13, PE6, PA2, PC5.
11. I/Os can be configured with internal pull-up, pull-down or floating in Shutdown mode but the configuration is lost when exiting the Shutdown mode.